

CD4024BM/CD4024BC 7-Stage Ripple Carry Binary Counter

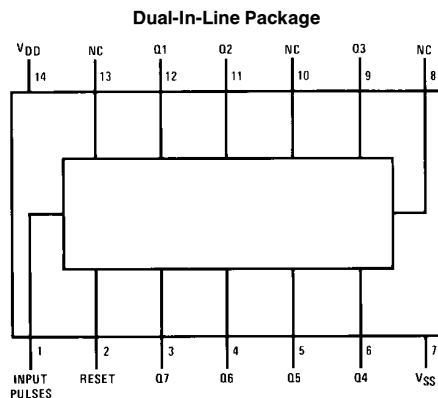
General Description

The CD4024BM/CD4024BC is a 7-stage ripple-carry binary counter. Buffered outputs are externally available from stages 1 through 7. The counter is reset to its logical "0" stage by a logical "1" on the reset input. The counter is advanced one count on the negative transition of each clock pulse.

Features

- Wide supply voltage range 3.0V to 15V
- High noise immunity 0.45 V_{DD} (typ.)
- Low power TTL compatibility Fan out of 2 driving 74L or 1 driving 74LS
- High speed 12 MHz (typ.)
- input pulse rate $V_{DD} - V_{SS} = 10V$
- Fully static operation

Connection Diagram

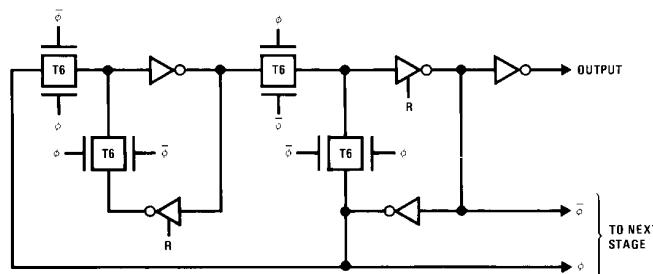


Order Number CD4024B

Top View

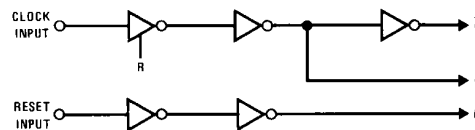
TL/F/5957-1

Schematic Diagrams



TL/F/5957-3

Input Logic



Flip-flop logic (1 of 7 identical stages).

TL/F/5957-4

Absolute Maximum Ratings (Notes 1 & 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

DC Supply Voltage (V_{DD})	−0.5 to +18 V_{DC}
Input Voltage (V_{IN})	−0.5 to V_{DD} + 0.5 V_{DC}
Storage Temperature Range (T_S)	−65°C to +150°C
Power Dissipation (P_D)	
Dual-In-Line	700 mW
Small Outline	500 mW
Lead Temp. (Soldering, 10 sec.) (T_L)	260°C

Recommended Operating Conditions (Note 2)

DC Supply Voltage (V_{DD})	+3 to +15 V_{DC}
Input Voltage (V_{IN})	0 to V_{DD} V_{DC}
Operating Temperature Range (T_A)	
CD4024BM	−55°C to +125°C
CD4024BC	−40°C to +85°C

DC Electrical Characteristics CD4024BM (Note 2)

Symbol	Parameter	Conditions	−55°C		+25°C			+125°C		Units
			Min	Max	Min	Typ	Max	Min	Max	
I_{DD}	Quiescent Device Current	$V_{DD} = 5V$		5		0.3	5		150	μA
		$V_{DD} = 10V$		10		0.5	10		300	μA
		$V_{DD} = 15V$		20		0.7	20		600	μA
V_{OL}	Low Level Output Voltage	$ I_O < 1 \mu A$								
		$V_{DD} = 5V$		0.05		0	0.05		0.05	V
		$V_{DD} = 10V$		0.05		0	0.05		0.05	V
V_{OH}	High Level Output Voltage	$ I_O < 1 \mu A$								
		$V_{DD} = 5V$	4.95		4.95	5		4.95		V
		$V_{DD} = 10V$	9.95		9.95	10		9.95		V
V_{IL}	Low Level Input Voltage	$ I_O < 1 \mu A$								
		$V_{DD} = 5V, V_O = 0.5V$ or 4.5V		1.5		2	1.5		1.5	V
		$V_{DD} = 10V, V_O = 1.0V$ or 9.0V		3.0		4	3.0		3.0	V
V_{IH}	High Level Input Voltage	$ I_O < 1 \mu A$								
		$V_{DD} = 5V, V_O = 0.5V$ or 4.5V	3.5		3.5	3		3.5		V
		$V_{DD} = 10V, V_O = 1.0V$ or 9.0V	7.0		7.0	6		7.0		V
I_{OL}	Low Level Output Current (Note 3)	$V_{DD} = 5V, V_O = 0.4V$	0.64		0.51	0.88		0.36		mA
		$V_{DD} = 10V, V_O = 0.5V$	1.6		1.3	2.25		0.9		mA
		$V_{DD} = 15V, V_O = 1.5V$	4.2		3.4	8.8		2.4		mA
I_{OH}	High Level Output Current (Note 3)	$V_{DD} = 5V, V_O = 4.6V$	−0.64		−0.51	−0.88		−0.36		mA
		$V_{DD} = 10V, V_O = 9.5V$	−1.6		−1.3	−2.25		−0.9		mA
		$V_{DD} = 15V, V_O = 13.5V$	−4.2		−3.4	−8.8		−2.4		mA
I_{IN}	Input Current	$V_{DD} = 15V, V_{IN} = 0V$		−0.10		10^{-5}	−0.10		−1.0	μA
		$V_{DD} = 15V, V_{IN} = 15V$		0.10		10^{-5}	0.10		1.0	μA

DC Electrical Characteristics CD4024BC (Note 2)

Symbol	Parameter	Conditions	−40°C		+25°C			+85°C		Units
			Min	Max	Min	Typ	Max	Min	Max	
I_{DD}	Quiescent Device Current	$V_{DD} = 5V$		20		0.3	20		150	μA
		$V_{DD} = 10V$		40		0.5	40		300	μA
		$V_{DD} = 15V$		60		0.7	80		600	μA
V_{OL}	Low Level Output Voltage	$ I_O < 1 \mu A$								
		$V_{DD} = 5V$		0.05		0	0.05		0.05	V
		$V_{DD} = 10V$		0.05		0	0.05		0.05	V
V_{OH}	High Level Output Voltage	$ I_O < 1 \mu A$								
		$V_{DD} = 5V$	4.95		4.95	5		4.95		V
		$V_{DD} = 10V$	9.95		9.95	10		9.95		V
V_{IL}	Low Level Input Voltage	$ I_O < 1 \mu A$								
		$V_{DD} = 5V, V_O = 0.5V$ or 4.5V		1.5		2	1.5		1.5	V
		$V_{DD} = 10V, V_O = 1.0V$ or 9.0V		3.0		4	3.0		3.0	V
V_{IH}	High Level Input Voltage	$ I_O < 1 \mu A$								
		$V_{DD} = 5V, V_O = 0.5V$ or 4.5V	3.5		3.5	3		3.5		V
		$V_{DD} = 10V, V_O = 1.0V$ or 9.0V	7.0		7.0	6		7.0		V
I_{OL}	Low Level Output Current (Note 3)	$V_{DD} = 5V, V_O = 0.4V$	0.64		0.51	0.88		0.36		mA
		$V_{DD} = 10V, V_O = 0.5V$	1.6		1.3	2.25		0.9		mA
		$V_{DD} = 15V, V_O = 1.5V$	4.2		3.4	8.8		2.4		mA
I_{OH}	High Level Output Current (Note 3)	$V_{DD} = 5V, V_O = 4.6V$	−0.64		−0.51	−0.88		−0.36		mA
		$V_{DD} = 10V, V_O = 9.5V$	−1.6		−1.3	−2.25		−0.9		mA
		$V_{DD} = 15V, V_O = 13.5V$	−4.2		−3.4	−8.8		−2.4		mA
I_{IN}	Input Current	$V_{DD} = 15V, V_{IN} = 0V$		−0.10		10^{-5}	−0.10		−1.0	μA
		$V_{DD} = 15V, V_{IN} = 15V$		0.10		10^{-5}	0.10		1.0	μA

DC Electrical Characteristics CD4024BC (Note 2) (Continued)

Symbol	Parameter	Conditions	−40°C		+25°C			+85°C		Units
			Min	Max	Min	Typ	Max	Min	Max	
V _{IL}	Low Level Input Voltage	I _O < 1 μA V _{DD} = 5V, V _O = 0.5V or 4.5V V _{DD} = 10V, V _O = 1.0V or 9.0V V _{DD} = 15V, V _O = 1.5V or 13.5V		1.5 3.0 4.0		2 4 6	1.5 3.0 4.0		1.5 3.0 4.0	V V V
V _{IH}	High Level Input Voltage	I _O < 1 μA V _{DD} = 5V, V _O = 0.5V or 4.5V V _{DD} = 10V, V _O = 1.0V or 9.0V V _{DD} = 15V, V _O = 1.5V or 13.5V	3.5 7.0 11.0		3.5 7.0 11.0	3 6 9		3.5 7.0 11.0		V V V
I _{OL}	Low Level Output Current (Note 3)	V _{DD} = 5V, V _O = 0.4V V _{DD} = 10V, V _O = 0.5V V _{DD} = 15V, V _O = 1.5V	0.52 1.3 3.6		0.44 1.1 3.0	0.88 2.25 8.8		0.36 0.9 2.4		mA mA mA
I _{OH}	High Level Output Current (Note 3)	V _{DD} = 5V, V _O = 4.6V V _{DD} = 10V, V _O = 9.5V V _{DD} = 15V, V _O = 13.5V	−0.52 −1.3 −3.6		−0.44 −1.1 −3.0	−0.88 −2.25 −8.8		−0.36 −0.9 −2.4		mA mA mA
I _{IN}	Input Current	V _{DD} = 15V, V _{IN} = 0V V _{DD} = 15V, V _{IN} = 15V		−0.30 0.30		−10 ^{−5} 10 ^{−5}	−0.30 0.30		−1.0 1.0	μA μA

AC Electrical Characteristics*

T_A = 25°C, C_L = 50 pF, R_L = 200 k, t_r and t_f = 20 ns unless otherwise specified

Symbol	Parameter	Conditions	Min	Typ	Max	Units
t _{PHL} , t _{PLH}	Propagation Delay Time to Q1 Output	V _{DD} = 5V V _{DD} = 10V V _{DD} = 15V		185 85 70	350 125 100	ns ns ns
t _{THL} , t _{TLH}	Transition Time	V _{DD} = 5V V _{DD} = 10V V _{DD} = 15V		100 50 40	200 100 80	ns ns ns
t _{WL} , t _{WH}	Minimum Input Pulse Width	V _{DD} = 5V V _{DD} = 10V V _{DD} = 15V		75 40 35	200 110 90	ns ns ns
t _{RCL} , t _{FCL}	Input Rise and Fall Time	V _{DD} = 5V V _{DD} = 10V V _{DD} = 15V			15 10 8	μs μs μs
f _{CL}	Maximum Input Pulse Frequency	V _{DD} = 5V V _{DD} = 10V V _{DD} = 15V	1.5 4 5	5 12 15		MHz MHz MHz
t _{PHL}	Reset Propagation Delay Time	V _{DD} = 5V V _{DD} = 10V V _{DD} = 15V		185 85 70	350 125 100	ns ns ns
t _{WH}	Reset Minimum Pulse Width	V _{DD} = 5V V _{DD} = 10V V _{DD} = 15V		185 85 70	350 125 100	ns ns ns
C _{IN}	Input Capacitance (Note 4)	Any Input		5	7.5	pF

*AC Parameters are guaranteed by DC correlated testing.

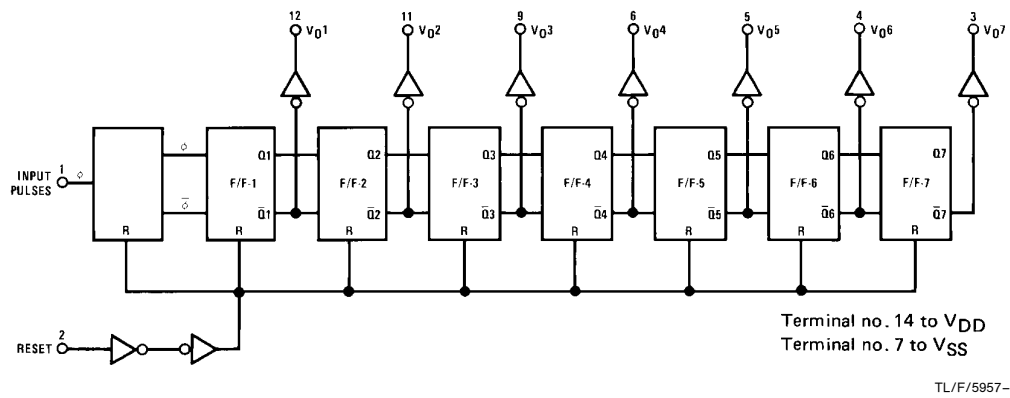
Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed, they are not meant to imply that the devices should be operated at these limits. The table of "Recommended Operating Conditions" and "Electrical Characteristics" provides conditions for actual device operation.

Note 2: V_{SS} = 0V unless otherwise specified.

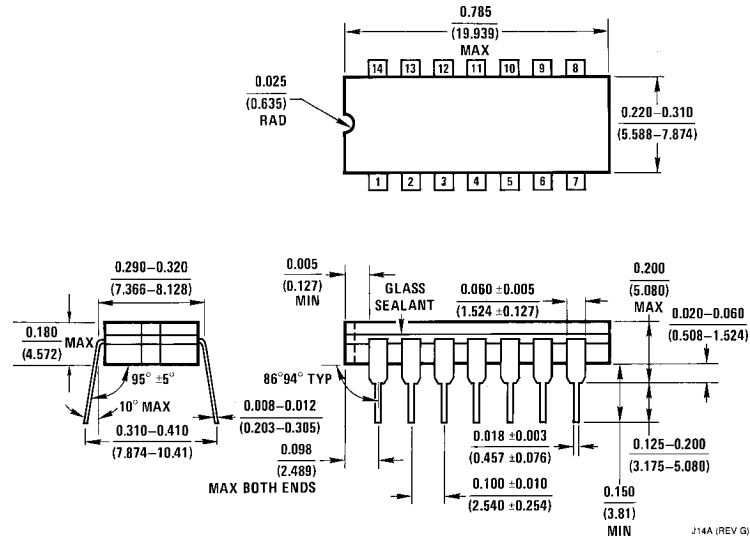
Note 3: I_{OH} and I_{OL} are tested one output at a time.

Note 4: Capacitance is guaranteed by periodic testing.

Logic Diagram

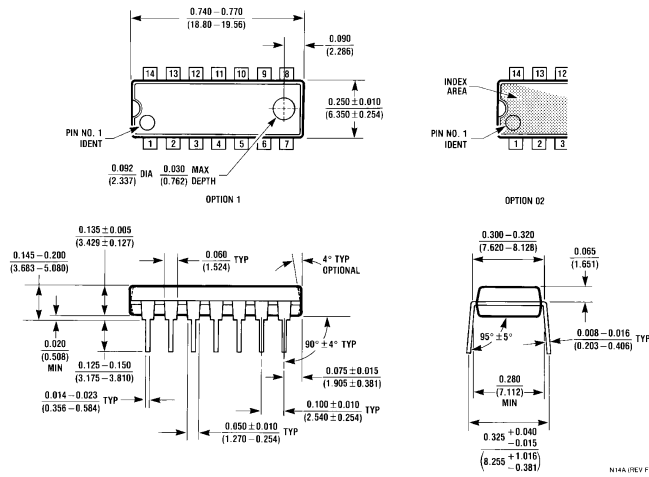


Physical Dimensions inches (millimeters)



Ceramic Dual-In-Line Package (J)
Order Number CD4024BMJ or CD402BCJ
NS Package Number J14A

Physical Dimensions inches (millimeters) (Continued)



Molded Dual-In-Line Package (N)
Order Number CD4024BMN or CD402BCN
NS Package Number N14A

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